

# SEMITOP<sup>®</sup> 3

3-phase bridge rectifier + brake chopper +3-phase bridge inverter SK 8 DGDL 065 ET

**Target Data** 

#### **Features**

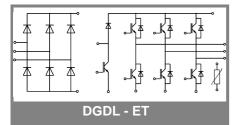
- · Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded alumium oxide ceramic (DCB)
- Ultrafast NPT technology IGBT
- CAL Technology FWD
- Integrated NTC temperature sensor

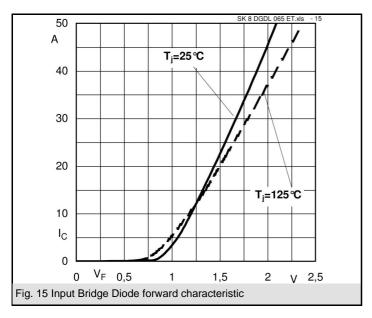
### **Typical Applications\***

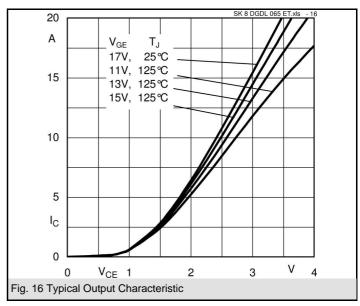
- Inverter
- Servo drives

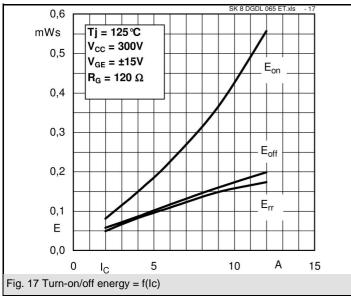
<b>Absolute Maximum Ratings</b> T <sub>s</sub> = 25°C, unless otherwise speci								
Symbol	Conditions	Values	Units					
IGBT - Inverter, Chopper								
V <sub>CES</sub>		600	V					
I <sub>C</sub>	T <sub>s</sub> = 25 (80) °C	12 (8)	Α					
I <sub>CRM</sub>	$I_{CRM} = 2 \times I_{Cnom}, t_p = 1 \text{ ms}$	12	Α					
$V_{GES}$		±20	V					
T <sub>j</sub>		-40 <b>+</b> 150	°C					
Diode - Inverter, Chopper								
I <sub>F</sub>	T <sub>s</sub> = 25 (80) °C	(13)	Α					
I <sub>FRM</sub>	$I_{FRM} = 2xI_{Fnom}, t_p = 1 \text{ ms}$	16	Α					
T <sub>j</sub>		-40 <b>+</b> 150	°C					
Rectifier								
$V_{RRM}$		1600	V					
I <sub>D</sub>	T <sub>s</sub> = 80 °C	33	Α					
I <sub>FSM</sub> / I <sub>TSM</sub>	$t_p = 10 \text{ ms}$ , sin 180 ° , $T_i = 25 \text{ °C}$		Α					
I <sup>2</sup> t	$t_p = 10 \text{ ms}, \sin 180  \text{°}, T_j = 25  \text{°C}$		A²s					
T <sub>j</sub>		-40 <b>+</b> 150	°C					
T <sub>sol</sub>	Terminals, 10s	260	°C					
T <sub>stg</sub>		-40 <b>+</b> 125	°C					
V <sub>isol</sub>	AC, 1 min. / 1s	2500 / 3000	V					

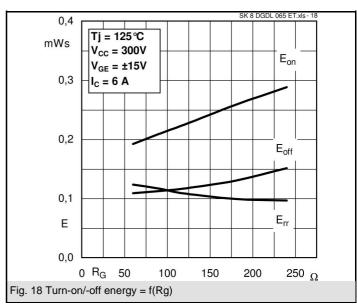
Characte	ristics	T <sub>s</sub> = 25°C	T <sub>s</sub> = 25°C, unless otherwise specified					
Symbol	Conditions	min.	typ.	max.	Units			
IGBT - Inverter, Chopper								
$V_{CEsat}$	I <sub>C</sub> = 6 A, T <sub>j</sub> = 25 (125) °C		2 (2,2)		V			
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 0.5$ mA	3	4	5	V			
$V_{CE(TO)}$	T <sub>j</sub> = 25 °C (125) °C		1,2 (1,1)		V			
$r_{T}$	T <sub>j</sub> = 25 °C (125) °C		133 (183)		mΩ			
C <sub>ies</sub>	$V_{CE} = 25 V_{GE} = 0 V, f = 1 MHz$		0,35		nF			
C <sub>oes</sub>	$V_{CE} = 25 V_{GE} = 0 V, f = 1 MHz$		0,04		nF			
C <sub>res</sub>	$V_{CE} = 25 V_{GE} = 0 V, f = 1 MHz$		0,03		nF			
$R_{th(j-s)}$	per IGBT			2,6	K/W			
$t_{d(on)}$	under following conditions		20		ns			
t <sub>r</sub>	$V_{CC} = 300 \text{ V}, V_{GE} = \pm 15 \text{ V}$		25		ns			
t <sub>d(off)</sub>	$I_C = 6 \text{ A}, T_j = 125 ^{\circ}\text{C}$		145		ns			
$t_{f}$	$R_{Gon} = R_{Goff} = 120 \Omega$		25		ns			
E <sub>on</sub>	inductive load		0,22		mJ			
E <sub>off</sub>			0,12		mJ			
	verter, Chopper							
$V_F = V_{EC}$	I <sub>F</sub> = 8 A, T <sub>i</sub> = 25(125) °C		1,35		V			
$V_{(TO)}$	$T_j = 25  ^{\circ}\text{C}  (125)  ^{\circ}\text{C}$		(8,0)	(0,9)	V			
r <sub>T</sub>	T <sub>j</sub> = 25 °C (125) °C		(44)		mΩ			
$R_{th(j-s)}$	per diode			2,7	K/W			
I <sub>RRM</sub>	under following conditions		4,2		Α			
$Q_{rr}$	I <sub>F</sub> = 8 A, V <sub>R</sub> = 300 V		0,65		μC			
E <sub>rr</sub>	$V_{GE} = 0 \text{ V}, T_j = 125 \text{ °C}$				mJ			
	di <sub>F/dt</sub> = -120 A/μs							
Diode red	tifier				•			
$V_{F}$	I <sub>F</sub> = 20 A, T <sub>i</sub> = 25() °C		1,45		V			
V <sub>(TO)</sub>	T <sub>i</sub> = 125 °C		0,82		V			
r <sub>T</sub>	T <sub>i</sub> = 125 °C		35		mΩ			
$R_{th(j-s)}$	per diode			2,8	K/W			
	Temperatur sensor							
R <sub>ts</sub>	5 %, T <sub>r</sub> = 25 (100 ) °C		5000(493)		Ω			
Mechanical data								
w			30		g			
$M_s$	Mounting torque	2,25		2,5	Nm			
	•	•			•			

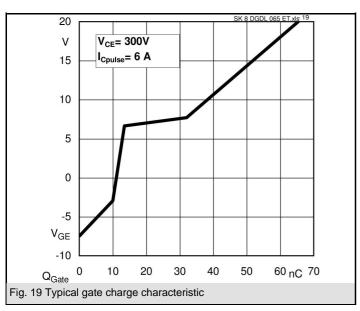


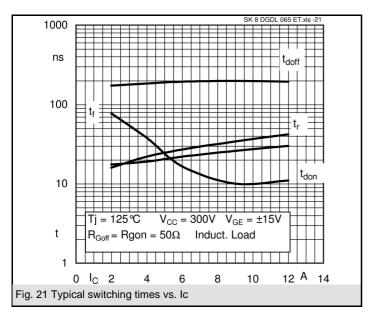


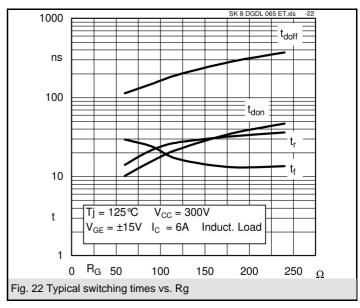


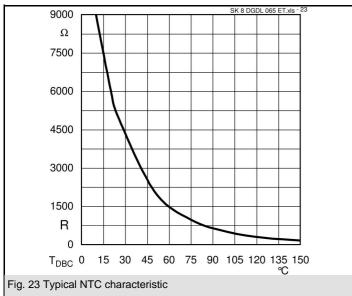


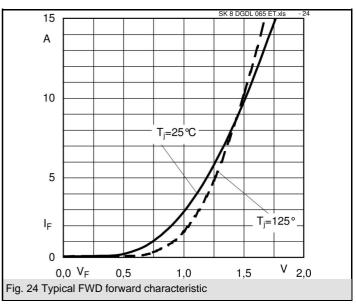


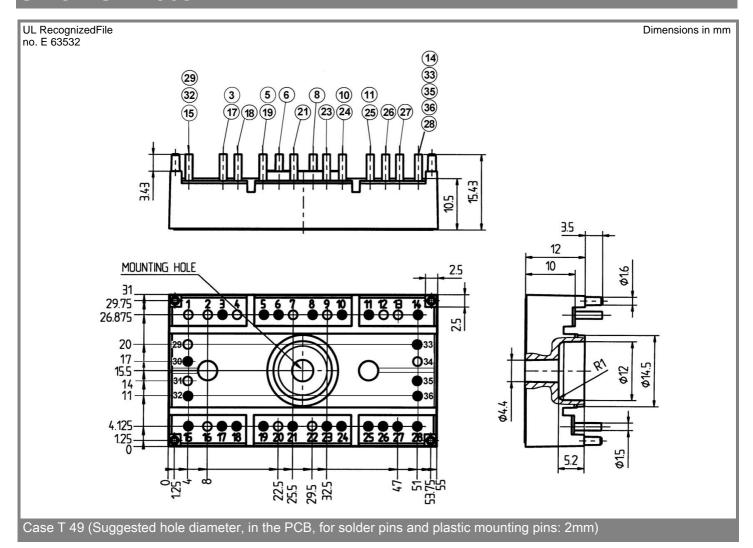


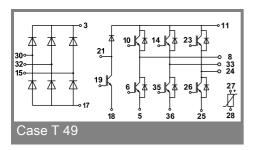












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

\* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.